

MOSFETs Silicon N-Channel MOS (U-MOSVII-H)

# SSM6K518NU

### 1. Applications

- · Power Management Switches
- · High-Speed Switching

#### 2. Features

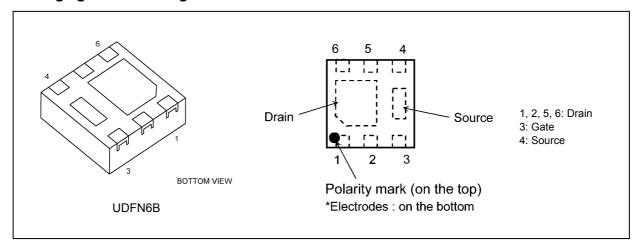
- (1) 1.5-V drive
- (2) Low drain-source on-resistance
  - $: R_{DS(ON)} = 33 \text{ m}\Omega \text{ (max) (@V_{GS} = 4.5 V)}$

 $R_{DS(ON)} = 45 \text{ m}\Omega \text{ (max) } (@V_{GS} = 2.5 \text{ V})$ 

 $R_{\rm DS(ON)} = 74 \ {\rm m}\Omega \ ({\rm max}) \ (@V_{\rm GS} = 1.8 \ {\rm V})$ 

 $R_{\mathrm{DS(ON)}} = 108 \ \mathrm{m}\Omega \ (\mathrm{max}) \ (@V_{\mathrm{GS}} = 1.5 \ \mathrm{V})$ 

### 3. Packaging and Pin Assignment





### 4. Absolute Maximum Ratings (Note) (Unless otherwise specified, Ta = 25 °C)

	Characteristics			Symbol	Rating	Unit
Drain-source voltage				$V_{DSS}$	20	V
Gate-source voltage				$V_{GSS}$	±8	
Drain current (DC)			(Note 1)	Ι <sub>D</sub>	6	Α
Drain current (pulsed)	·		(Note 1), (Note 2)	$I_{DP}$	24	
Power dissipation			(Note 3)	$P_D$	1.25	W
Power dissipation	(t :	≤ 10 s)	(Note 3)		2.5	
Channel temperature				T <sub>ch</sub>	150	°C
Storage temperature	,			T <sub>stg</sub>	-55 to 150	ů

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- Note 1: Ensure that the channel temperature does not exceed 150 °C.
- Note 2: Pulse width (PW)  $\leq$  10 ms, duty = 1 %
- Note 3: Device mounted on a 25.4 mm × 25.4 mm × 1.6 mm FR4 glass epoxy board (Cu pad: 645 mm<sup>2</sup>)

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

Note: The MOSFETs in this device are sensitive to electrostatic discharge. When handling this device, the worktables, operators, soldering irons and other objects should be protected against anti-static discharge.

Note: The channel-to-ambient thermal resistance, R<sub>th(ch-a)</sub>, and the drain power dissipation, P<sub>D</sub>, vary according to the board material, board area, board thickness and pad area. When using this device, be sure to take heat dissipation fully into account.



#### 5. Electrical Characteristics

### 5.1. Static Characteristics (Unless otherwise specified, Ta = 25 °C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 6 \text{ V}$	_	_	±1	μА
Drain cut-off current		I <sub>DSS</sub>	V <sub>DS</sub> = 16 V, V <sub>GS</sub> = 0 V	_	_	1	
Drain-source breakdown voltage		V <sub>(BR)DSS</sub>	I <sub>D</sub> = 1 mA, V <sub>GS</sub> = 0 V	20	_		V
Drain-source breakdown voltage	(Note 1)	V <sub>(BR)DSX</sub>	I <sub>D</sub> = 1 mA, V <sub>GS</sub> = -5 V	15	_		
Gate threshold voltage	(Note 2)	V <sub>th</sub>	$V_{DS} = 3 \text{ V}, I_{D} = 1 \text{ mA}$	0.4	_	1.0	
Drain-source on-resistance	(Note 3)	R <sub>DS(ON)</sub>	I <sub>D</sub> = 0.5 A, V <sub>GS</sub> = 1.5 V	_	54	108	mΩ
			I <sub>D</sub> = 0.5 A, V <sub>GS</sub> = 1.8 V	_	40	74	
			I <sub>D</sub> = 1.0 A, V <sub>GS</sub> = 2.5 V	_	31	45	
			I <sub>D</sub> = 4.0 A, V <sub>GS</sub> = 4.5 V	_	25	33	
Forward transfer admittance	(Note 3)	Y <sub>fs</sub>	V <sub>DS</sub> = 3 V, I <sub>D</sub> = 2 A	_	12		S

Note 1: If a reverse bias is applied between gate and source, this device enters  $V_{(BR)DSX}$  mode. Note that the drain-source breakdown voltage is lowered in this mode.

Note 2: Let  $V_{th}$  be the voltage applied between gate and source that causes the drain current ( $I_D$ ) to below (0.1 mA for this device). Then, for normal switching operation,  $V_{GS(ON)}$  must be higher than  $V_{th}$ , and  $V_{GS(OFF)}$  must be lower than  $V_{th}$ . This relationship can be expressed as:  $V_{GS(OFF)} < V_{th} < V_{GS(ON)}$ .

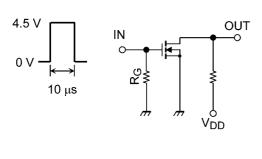
Take this into consideration when using the device.

Note 3: Pulse measurement.

### 5.2. Dynamic Characteristics (Unless otherwise specified, T<sub>a</sub> = 25 °C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C <sub>iss</sub>	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V},$	_	410	_	pF
Reverse transfer capacitance	C <sub>rss</sub>	f = 1 MHz	_	40		
Output capacitance	Coss		_	85		
Switching time (turn-on time)	t <sub>on</sub>	$V_{DD} = 10 \text{ V}, I_D = 0.5 \text{ A},$ $V_{GS} = 0 \text{ to } 4.5 \text{ V}, R_G = 10 \Omega$	_	25		ns
Switching time (turn-off time)	t <sub>off</sub>	Duty $\leq$ 1 %,Input: $t_r$ , $t_f$ < 5 ns, Common source, See Chapter 5.3.	_	45		

### 5.3. Switching Time Test Circuit



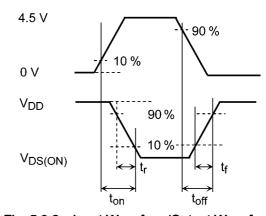


Fig. 5.3.1 Switching Time Test Circuit

Fig. 5.3.2 Input Waveform/Output Waveform



### 5.4. Gate Charge Characteristics (Unless otherwise specified, Ta = 25 °C)

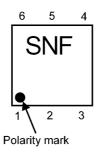
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Qg	$V_{DD} = 8 \text{ V}, I_{D} = 4 \text{ A},$	_	3.6		nC
Gate-source charge 1	Q <sub>gs1</sub>	V <sub>GS</sub> = 4.5 V	_	0.62		
Gate-drain charge	Q <sub>gd</sub>		_	0.79		

### 5.5. Source-Drain Characteristics (Unless otherwise specified, T<sub>a</sub> = 25 °C)

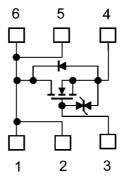
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Diode forward voltage	(Note 1)	$V_{DSF}$	$I_D = -4 A, V_{GS} = 0 V$	_	-0.8	-1.2	V

Note 1: Pulse measurement.

### 6. Marking



### 7. Internal Circuit





### 8. Characteristics Curves (Note)

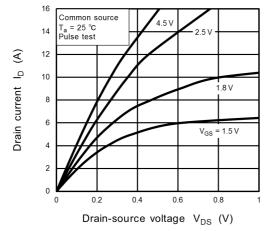


Fig. 8.1 I<sub>D</sub> - V<sub>DS</sub>

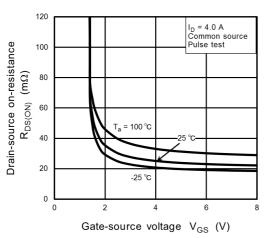


Fig. 8.3 R<sub>DS(ON)</sub> - V<sub>GS</sub>

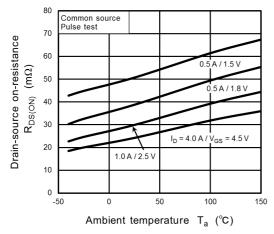


Fig. 8.5 R<sub>DS(ON)</sub> - T<sub>a</sub>

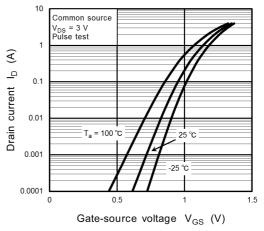


Fig. 8.2 I<sub>D</sub> - V<sub>GS</sub>

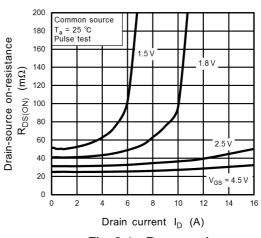


Fig. 8.4 R<sub>DS(ON)</sub> - I<sub>D</sub>

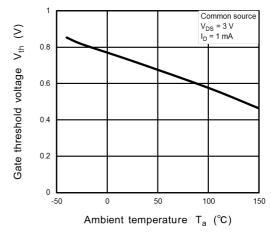


Fig. 8.6 V<sub>th</sub> - T<sub>a</sub>



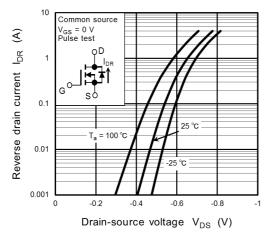


Fig. 8.7 IDR - VDS

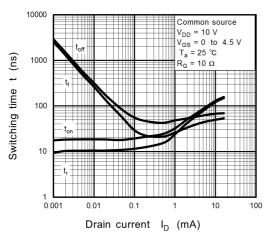


Fig. 8.9 t-I<sub>D</sub>

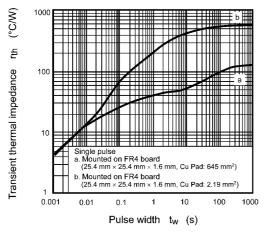


Fig. 8.11 rth - tw

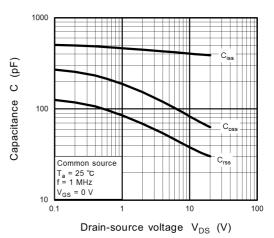


Fig. 8.8 C - V<sub>DS</sub>

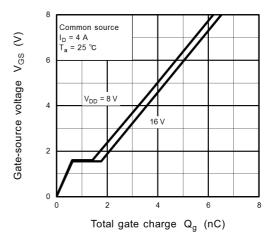


Fig. 8.10 Dynamic Input Characteristics

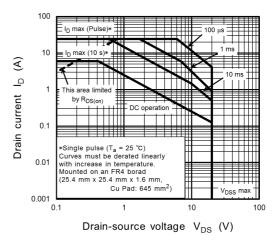


Fig. 8.12 Safe Operating Area

Rev.1.0



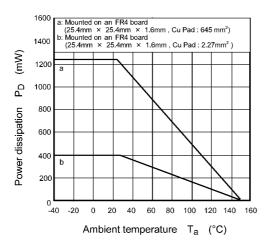


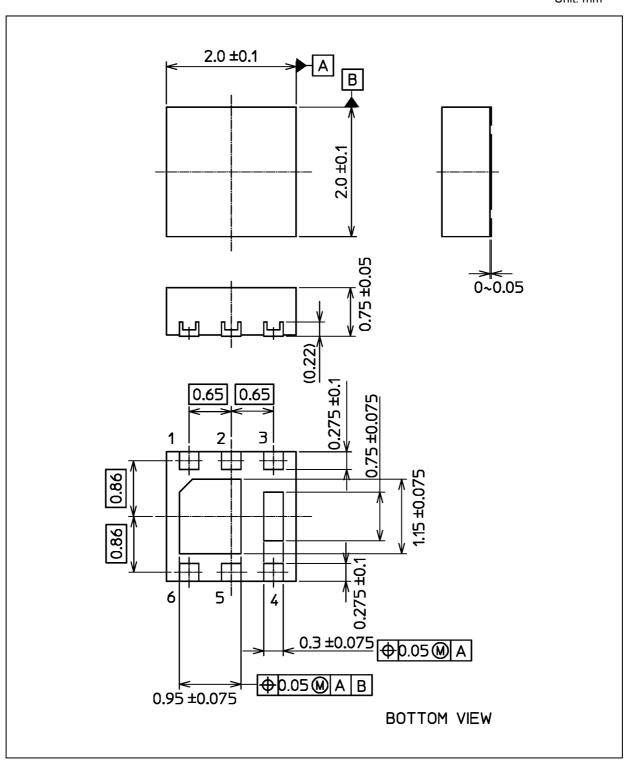
Fig. 8.13 PD - Ta

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



### **Package Dimensions**

Unit: mm



Weight: 8.5 mg (typ.)

	Package Name(s)
Nickname: UDFN6B	



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